

Automotive-grade high voltage ignition coil driver NPN power Darlington transistor

Datasheet - production data

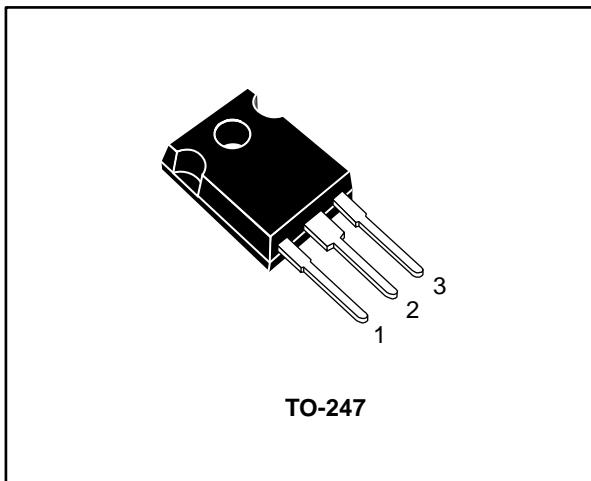


Figure 1: Internal schematic diagram

Features



- AEC-Q101 qualified
- Very rugged Bipolar technology
- High operating junction temperature

Applications

- High ruggedness electronic ignitions

Description

This is a high voltage power Darlington transistor developed using multi epitaxial planar technology. It has been properly designed for automotive environment as electronic ignition power actuators.

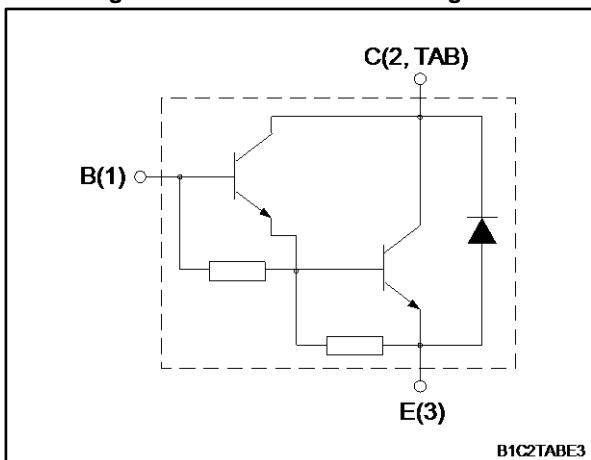


Table 1: Device summary

Order code	Marking	Package	Packing
BU931P	BU931P	TO-247	Tube

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1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	500	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	5	V
I_C	Collector current	15	A
I_{CM}	Collector peak current	30	A
I_B	Base current	1	A
I_{BM}	Base peak current	5	A
P_{TOT}	Total dissipation at $T_c = 25^\circ\text{C}$	135	W
T_{stg}	Storage temperature range	-65 to 175	$^\circ\text{C}$
T_j	Operating junction temperature range		$^\circ\text{C}$

Table 3: Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Thermal resistance junction-case	1.1	$^\circ\text{C}/\text{W}$
R_{thJA}	Thermal resistance junction-ambient	50	$^\circ\text{C}/\text{W}$

2 Electrical characteristics

($T_C = 25^\circ\text{C}$ unless otherwise specified)

Table 4: Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current	$V_{BE} = 0 \text{ V}, V_{CE} = 500 \text{ V}$		-	100	μA
		$V_{BE} = 0 \text{ V}, V_{CE} = 500 \text{ V}, T_C = 125^\circ\text{C}$ (1)		-	0.5	mA
I_{CEO}	Collector cut-off current	$I_B = 0 \text{ A}, V_{CE} = 450 \text{ V}$		-	100	μA
		$I_B = 0 \text{ A}, V_{CE} = 450 \text{ V}, T_C = 125^\circ\text{C}$ (1)		-	0.5	mA
I_{EBO}	Emitter cut-off current	$I_C = 0 \text{ A}, V_{EB} = 5 \text{ V}$		-	20	mA
$V_{CEO(sus)}$ (2)	Collector-emitter sustaining voltage	$I_B = 0 \text{ A}, I_C = 100 \text{ mA}$	400	-		V
$V_{CE(sat)}$ (2)	Collector-emitter saturation voltage	$I_C = 7 \text{ A}, I_B = 70 \text{ mA}$		-	1.6	V
		$I_C = 8 \text{ A}, I_B = 100 \text{ mA}$		-	1.8	V
		$I_C = 10 \text{ A}, I_B = 250 \text{ mA}$		-	1.8	V
$V_{BE(sat)}$ (2)	Base-emitter saturation voltage	$I_C = 7 \text{ A}, I_B = 70 \text{ mA}$		-	2.2	V
		$I_C = 8 \text{ A}, I_B = 100 \text{ mA}$		-	2.4	V
		$I_C = 10 \text{ A}, I_B = 250 \text{ mA}$		-	2.5	V
h_{FE} (2)	DC current gain	$I_C = 5 \text{ A}, V_{CE} = 10 \text{ V}$	300	-		
V_F	Diode forward voltage	$I_F = 10 \text{ A}$		-	2.5	V
	Functional test	$V_{CC} = 24 \text{ V}, L = 7 \text{ mH}, V_{clamp} = 400 \text{ V}$ (see Figure 10: "Functional test circuit")	8	-		A

Notes:

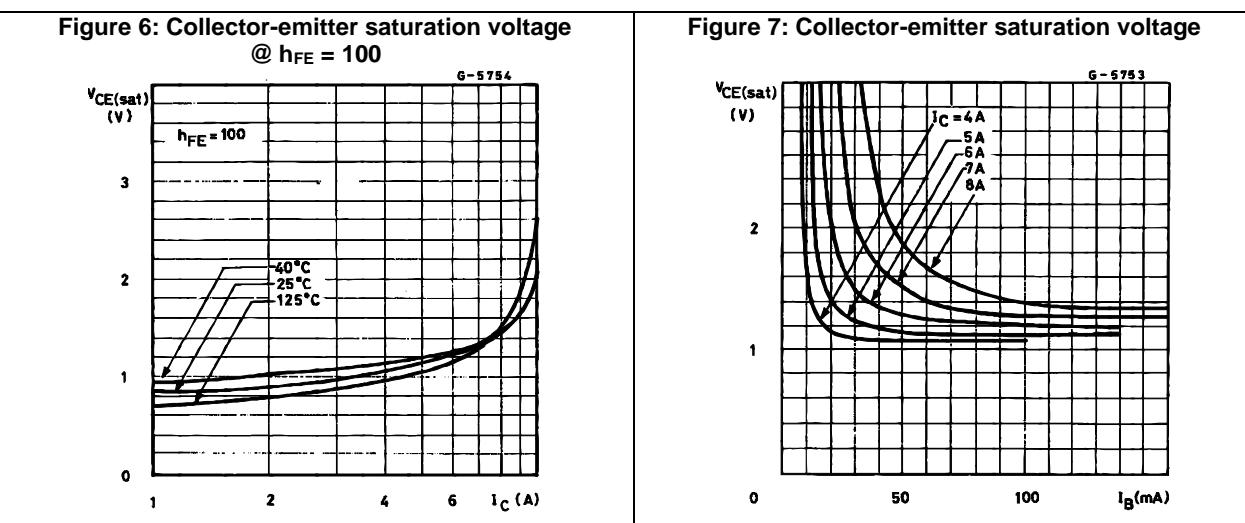
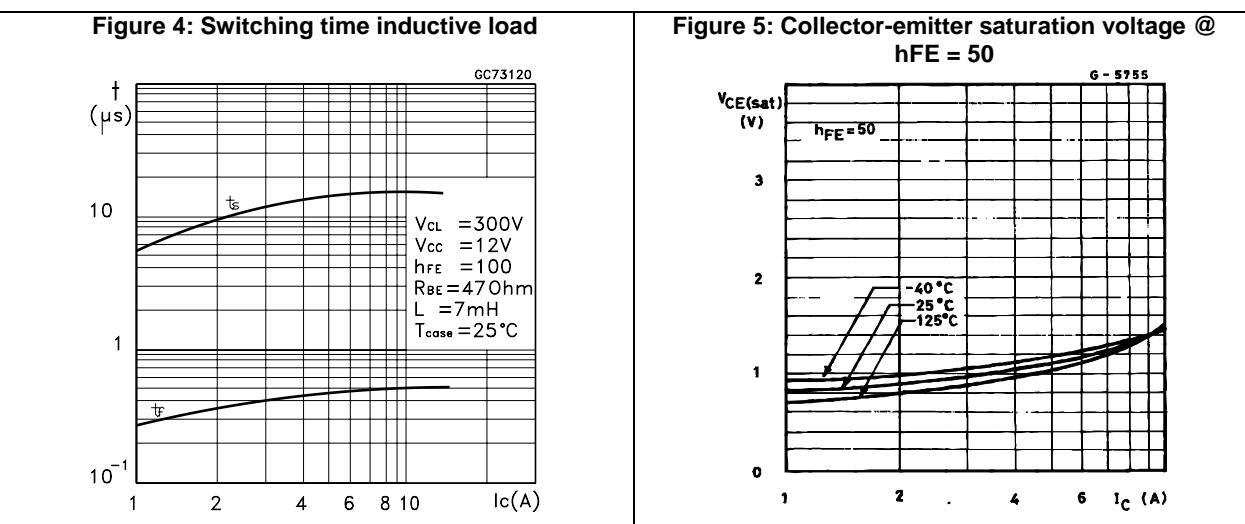
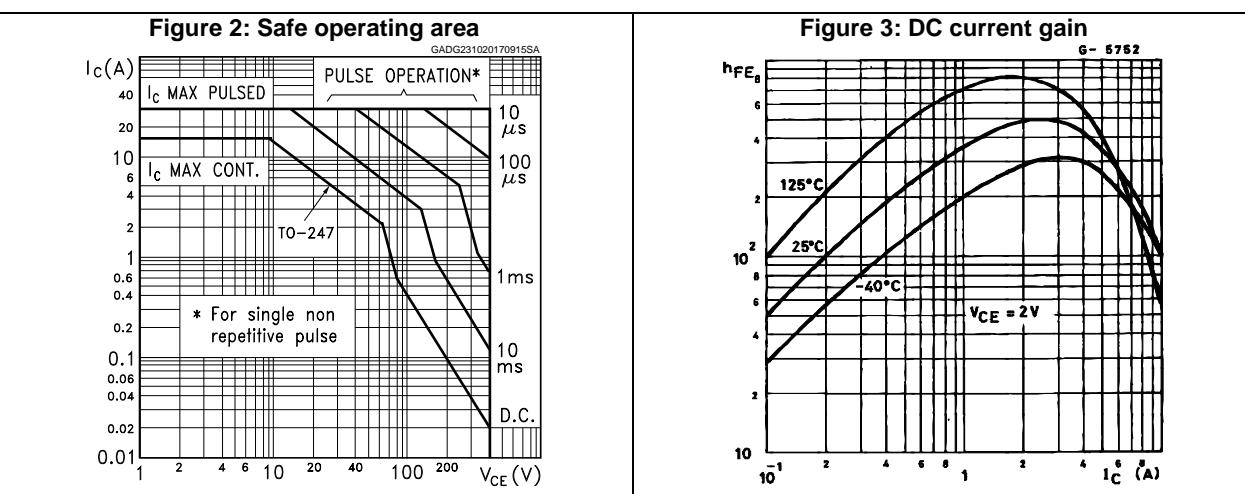
(1)Defined by design, not subject to production test.

(2)Pulse test: pulse duration $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$.

Table 5: Inductive load switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
t_s	Storage time	$V_{BE}=0, V_{CC} = 12 \text{ V}, V_{clamp} = 300 \text{ V}, L = 7 \text{ mH}, R_{BE} = 47 \Omega, I_C = 7 \text{ A}, I_B = 70 \text{ mA}$ (see Figure 12: "Switching time test circuit")	-	15	-	μs
t_f	Fall time		-	0.5	-	μs

2.1 Electrical characteristics (curves)



Electrical characteristics

BU931P

Figure 8: Base-emitter saturation voltage
@ $h_{FE} = 50$

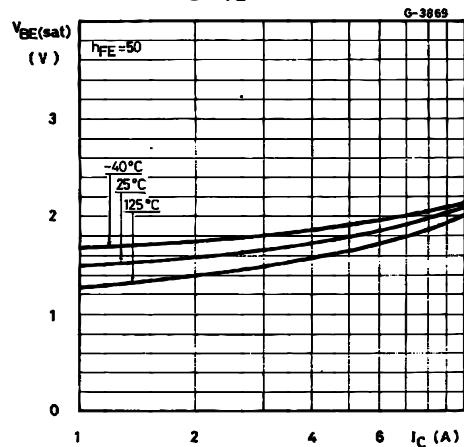
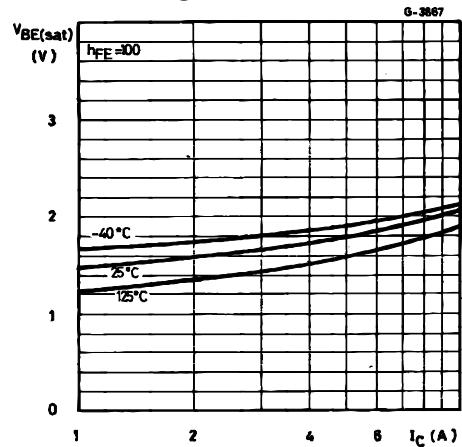


Figure 9: Base-emitter saturation voltage
@ $h_{FE} = 100$



3 Test circuits

Figure 10: Functional test circuit

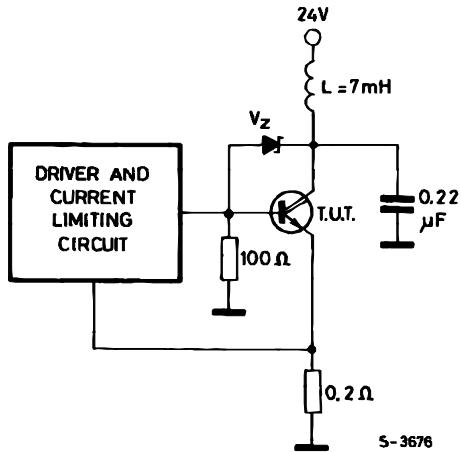


Figure 11: Functional test waveforms

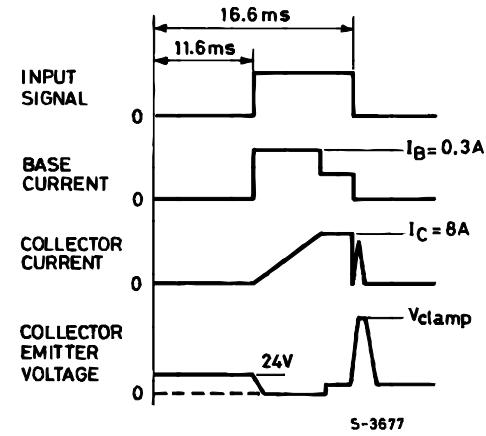


Figure 12: Switching time test circuit

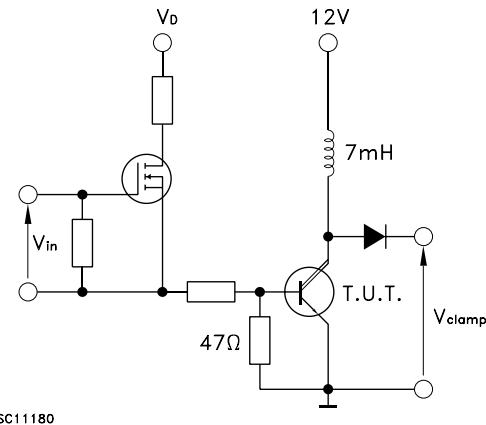
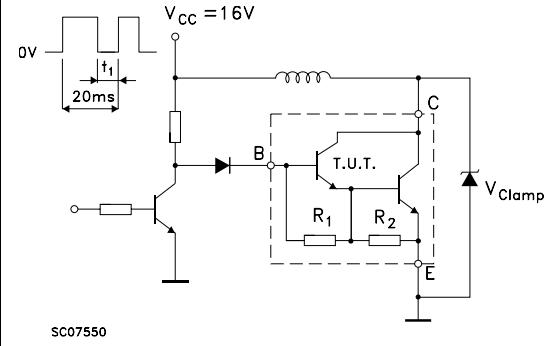


Figure 13: Sustaining voltage test circuit

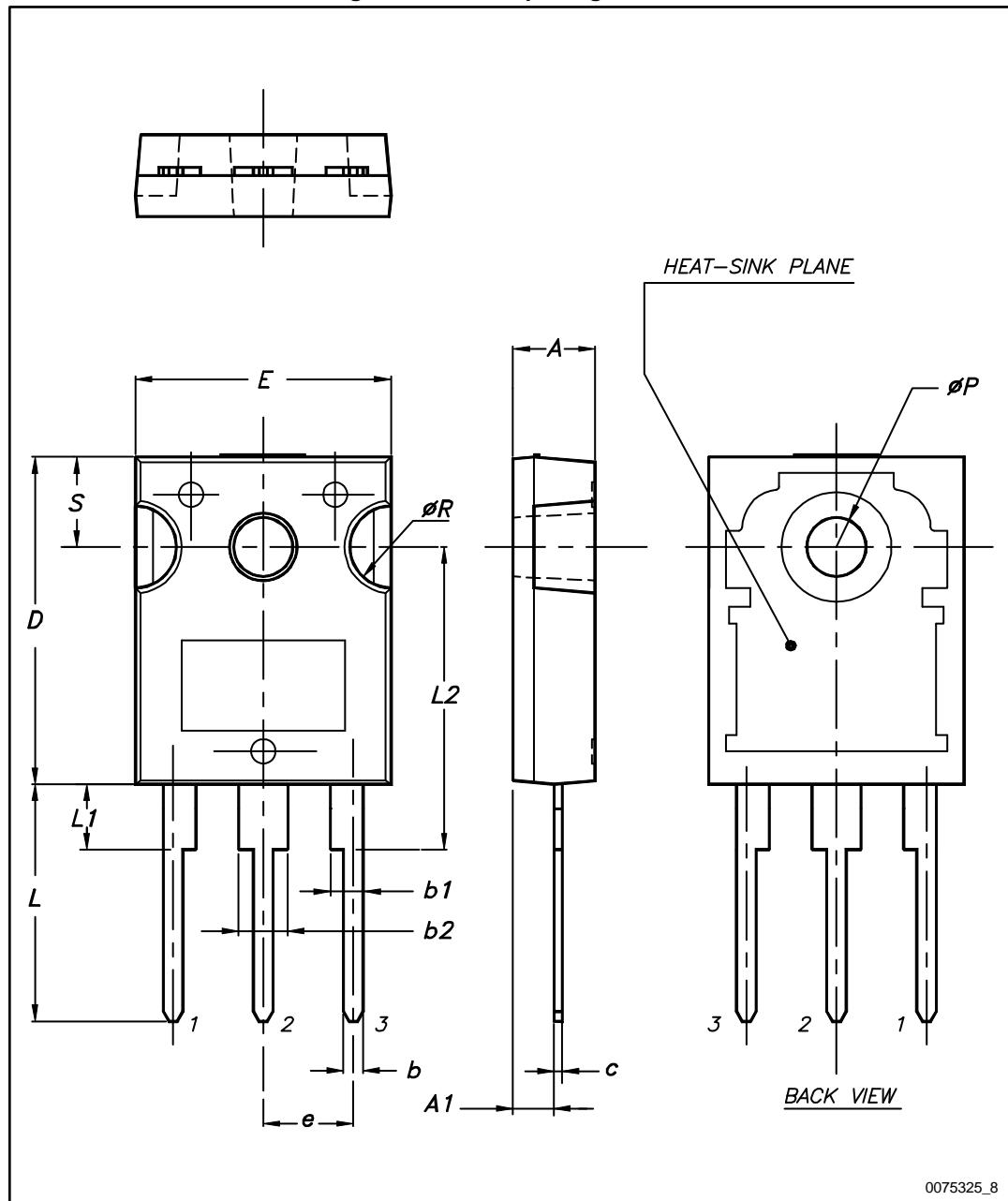


4 Package information

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4.1 TO-247 package information

Figure 14: TO-247 package outline



0075325_8

Table 6: TO-247 package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.85		5.15
A1	2.20		2.60
b	1.0		1.40
b1	2.0		2.40
b2	3.0		3.40
c	0.40		0.80
D	19.85		20.15
E	15.45		15.75
e	5.30	5.45	5.60
L	14.20		14.80
L1	3.70		4.30
L2		18.50	
ØP	3.55		3.65
ØR	4.50		5.50
S	5.30	5.50	5.70

5 Revision history

Table 7: Document revision history

Date	Revision	Changes
23-Oct-2017	1	Initial release. Part number previously included in datasheet DocID1004.

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